L Number	Hits	Search Text	DB	Time stamp
4	1391	349/149	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 10:17
5	63808	terminal near3 electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 10:20
6	335	349/149 and (terminal near3 electrode)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 10:17
7	99	((liquid near3 crystal) or lcd) and ((tft or (thin near3 film near3 transistor)) near6 substrate) and (pixel near3 electrode) and switch$4 and ((source and gate) near4 line) and ((display and terminal) near5 area)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 10:19
8	65	(terminal near3 electrode) and (((liquid near3 crystal) or lcd) and ((tft or (thin near3 film near3 transistor)) near6 substrate) and (pixel near3 electrode) and switch$4 and ((source and gate) near4 line) and ((display and terminal) near5 area))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 10:19
9	4	((terminal near3 electrode) and (((liquid near3 crystal) or lcd) and ((tft or (thin near3 film near3 transistor)) near6 substrate) and (pixel near3 electrode) and switch$4 and ((source and gate) near4 line) and ((display and terminal) near5 area))) and 349/149	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 10:19
11	12497	terminal adj electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 10:20
12	8	(terminal adj electrode) and ((terminal near3 electrode) and (((liquid near3 crystal) or lcd) and ((tft or (thin near3 film near3 transistor)) near6 substrate) and (pixel near3 electrode) and switch$4 and ((source and gate) near4 line) and ((display and terminal) near5 area)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 10:21
13	8	(terminal adj electrode) and (((liquid near3 crystal) or lcd) and ((tft or (thin near3 film near3 transistor)) near6 substrate) and (pixel near3 electrode) and switch$4 and ((source and gate) near4 line) and ((display and terminal) near5 area))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/17 10:21
-	1282	349/149	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/15 15:24
-	1234	((liquid near3 crystal) or lcd) and (tft or (thin near3 film near3 transistor)) and substrate and electrode and switch$4 and ((source and gate) near4 line)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/15 16:29

-	747	(((liquid near3 crystal) or lcd) and (tft or (thin near3 film near3 transistor)) and substrate and electrode and switch$4 and ((source and gate) near4 line)) and terminal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/15 16:29
-	50	((liquid near3 crystal) or lcd) and (tft or (thin near3 film near3 transistor)) and (pixel near3 electrode) and switch$4 and ((gate and source and metal$4) near3 line) and insulat$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/16 11:32
-	35	((liquid near3 crystal) or lcd) and (tft or (thin near3 film near3 transistor)) and (pixel near3 electrode) and switch$4 and ((gate and source and metal$4) near3 line) and insulat$3 and hole	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/16 11:36
-	33	((liquid near3 crystal) or lcd) and (tft or (thin near3 film near3 transistor)) and (pixel near3 electrode) and switch$4 and ((gate and source and metal$4) near3 line) and insulat$3 and (contact near4 hole)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/16 11:52